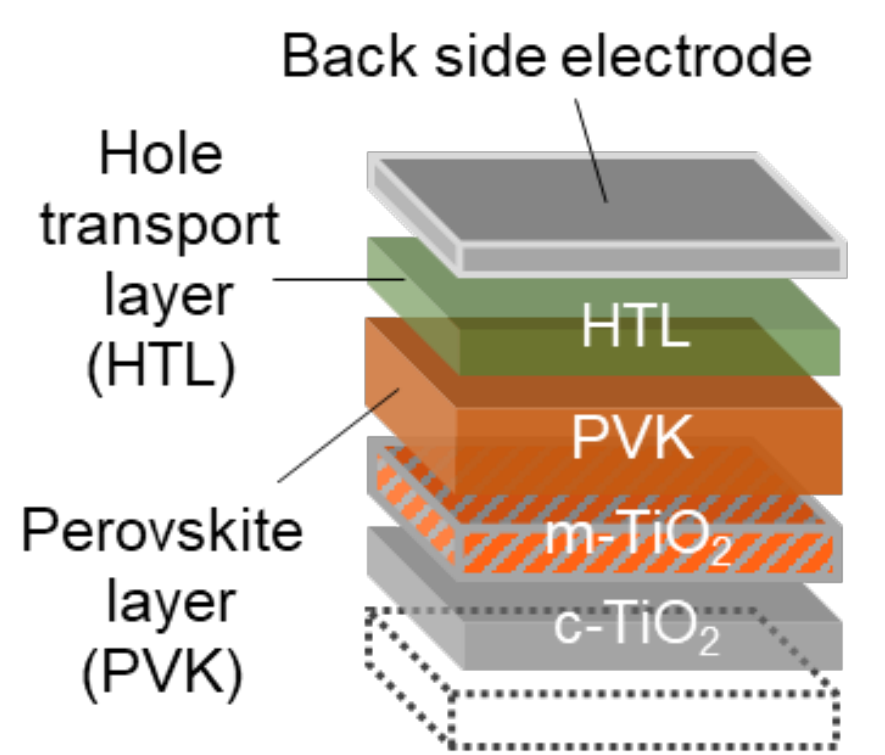


非ハロゲン系溶媒に可溶なドーパントフリーホール輸送材料を用いたペロブスカイト太陽電池

Introduction

Perovskite solar Cell (PSC)



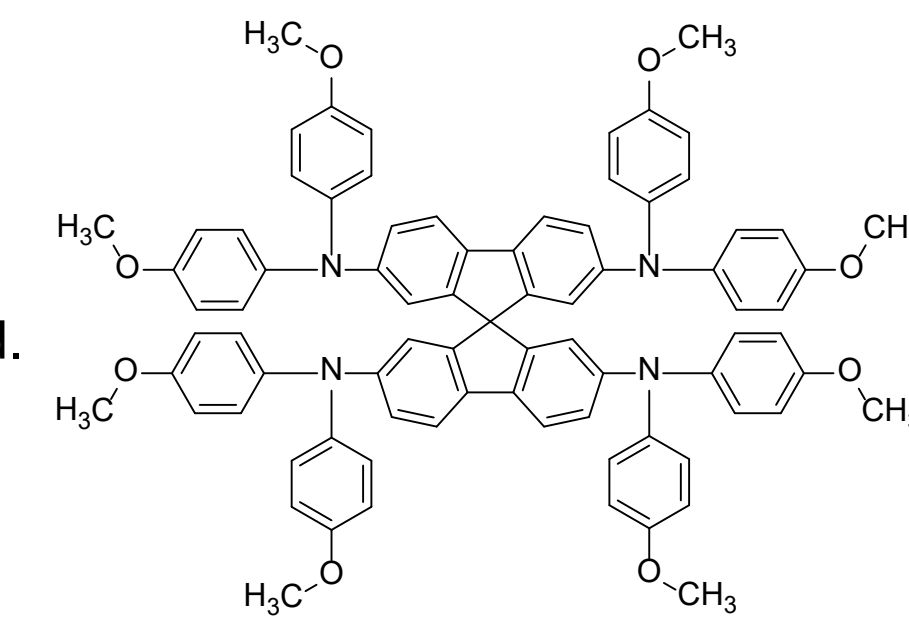
- High power conversion efficiency
- Easy fabrication
- Low cost

HTMs have been actively explored. The exploration mainly focused on the following three characteristics:

- 1) Long-term stability.
- 2) High hole mobility.
- 3) Suitable frontier energy levels matching that of perovskite layer.

Figure 1 Typical mesoporous-type device structure.

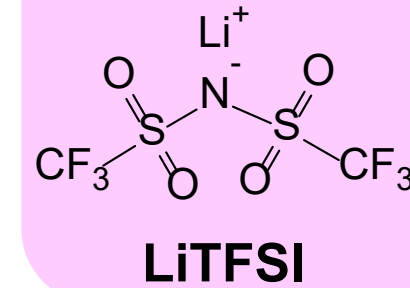
Typical organic HTM for PSC



Spiro-OMeTAD

Some dopants (ionic compound, base etc.) are needed to introduce more charge carriers.

Dopants

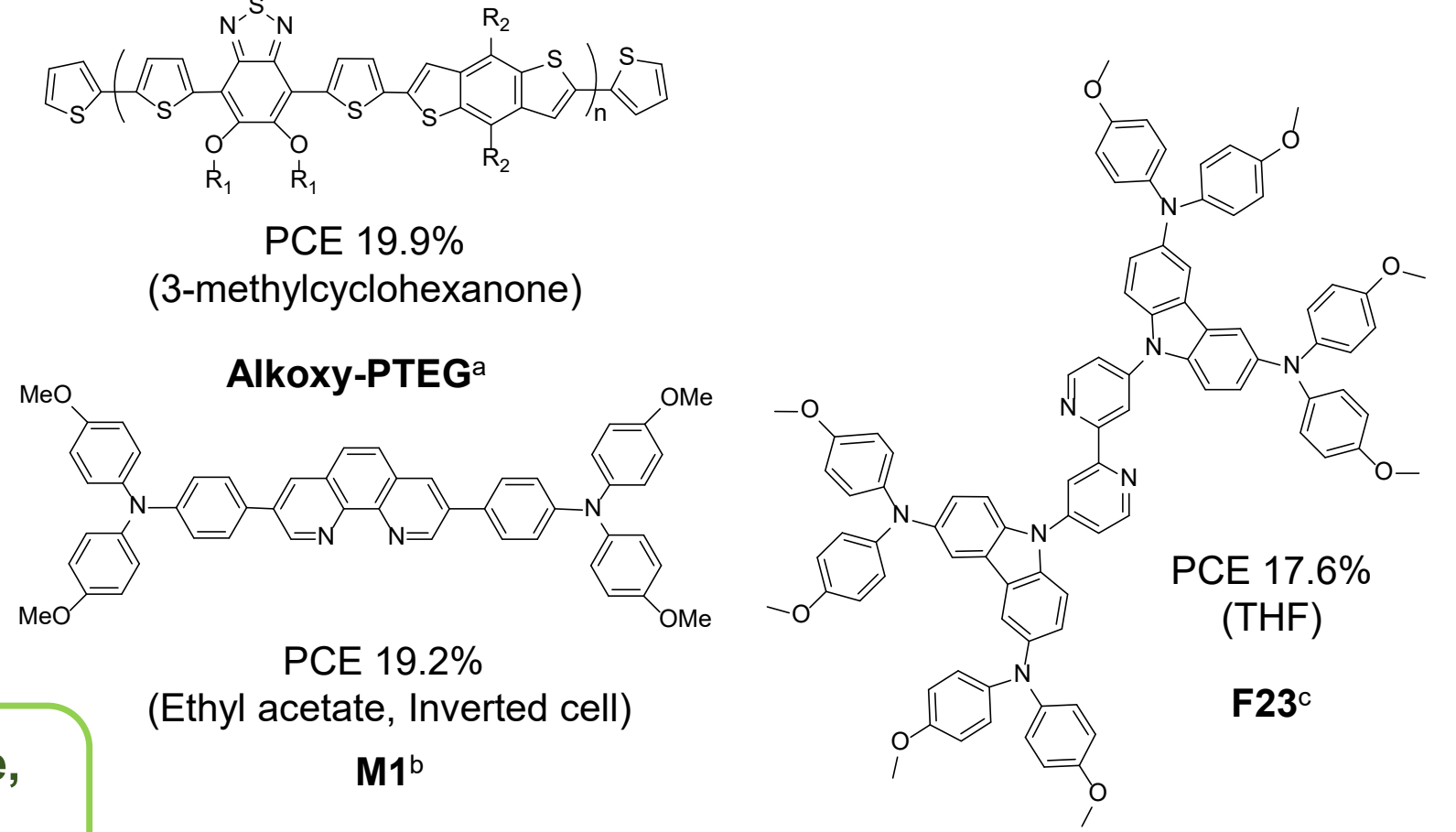


Hygroscopic, volatile
Device degradation

Most of organic HTMs are processed with chlorinated solvents such as chlorobenzene (CB).

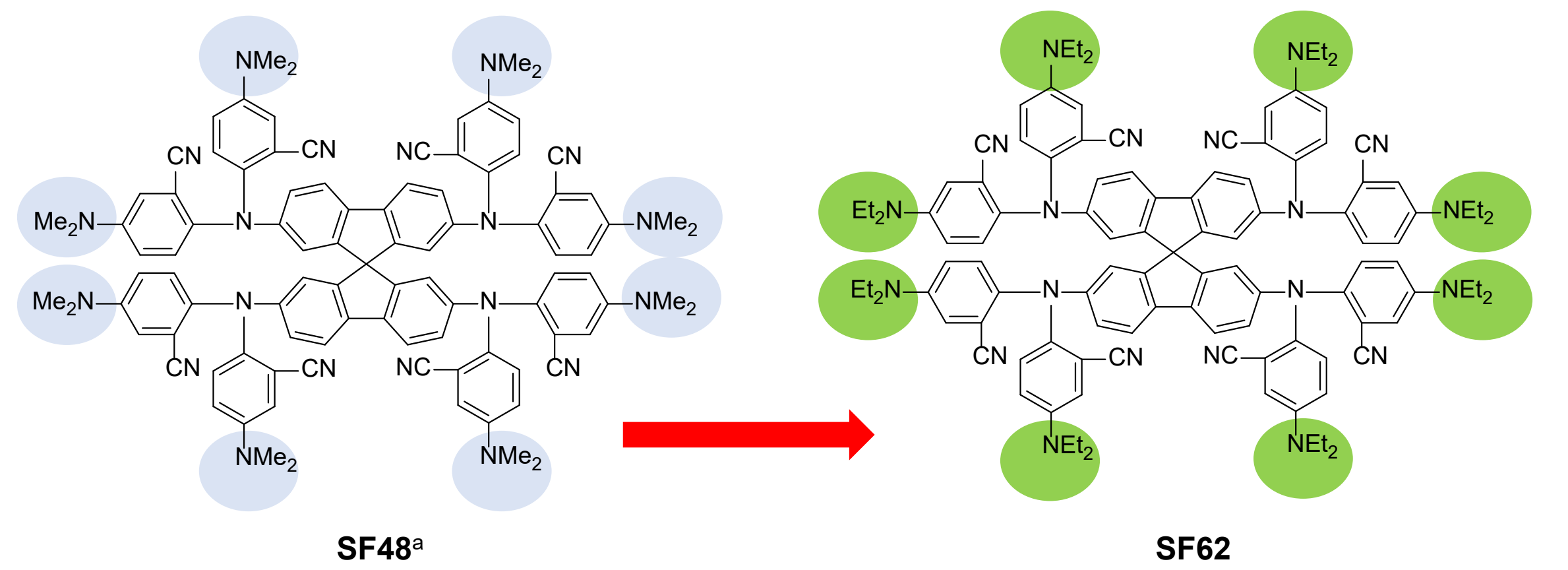
Nonhalogenated-solvent (green-solvent)-soluble, dopant-free HTMs are desirable for the practical application of PSCs.

Green-solvent-soluble dopant-free HTMs



^a J. Lee et al, *Adv. Energy Mater.*, 2020, 10, 1902662.
^b J. Huang et al, *J. Mater. Chem. C*, 2021, 9, 8930.
^c H. Lu et al, *Energy. Environ. Sci.*, 2020, 385, 123976.

Our Work



SF62 is soluble in green solvent such as AcOEt because of large hydrophobic groups.

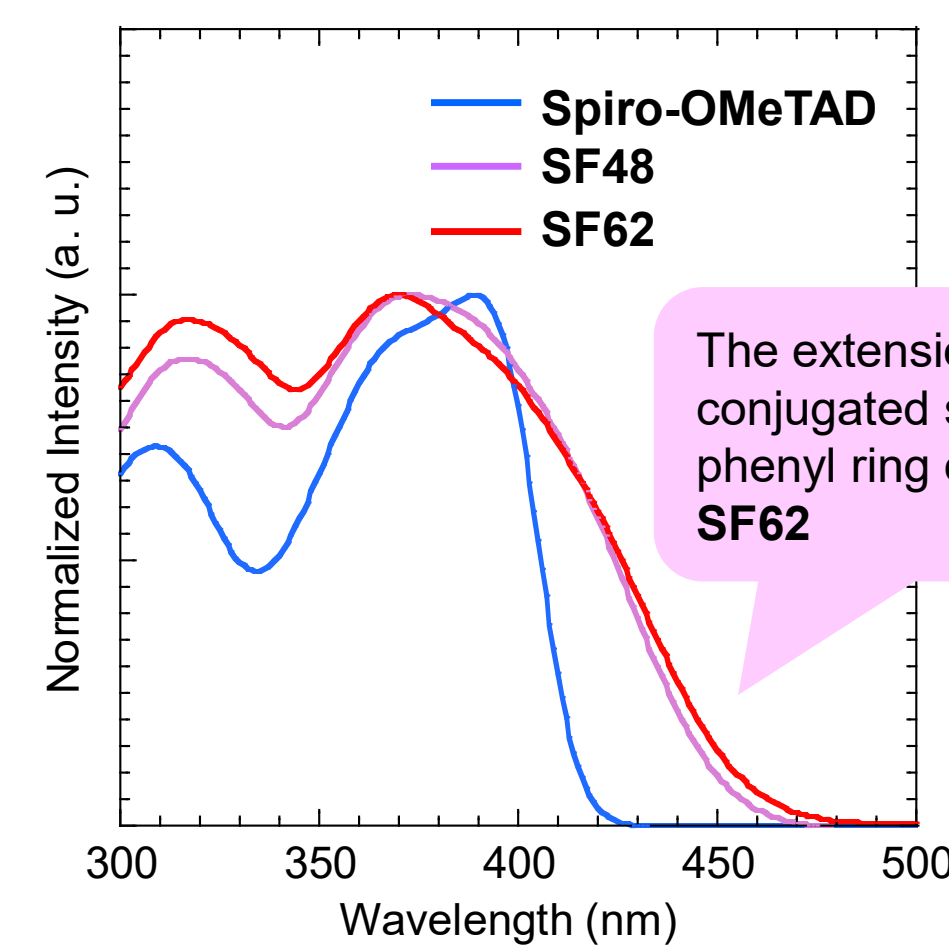
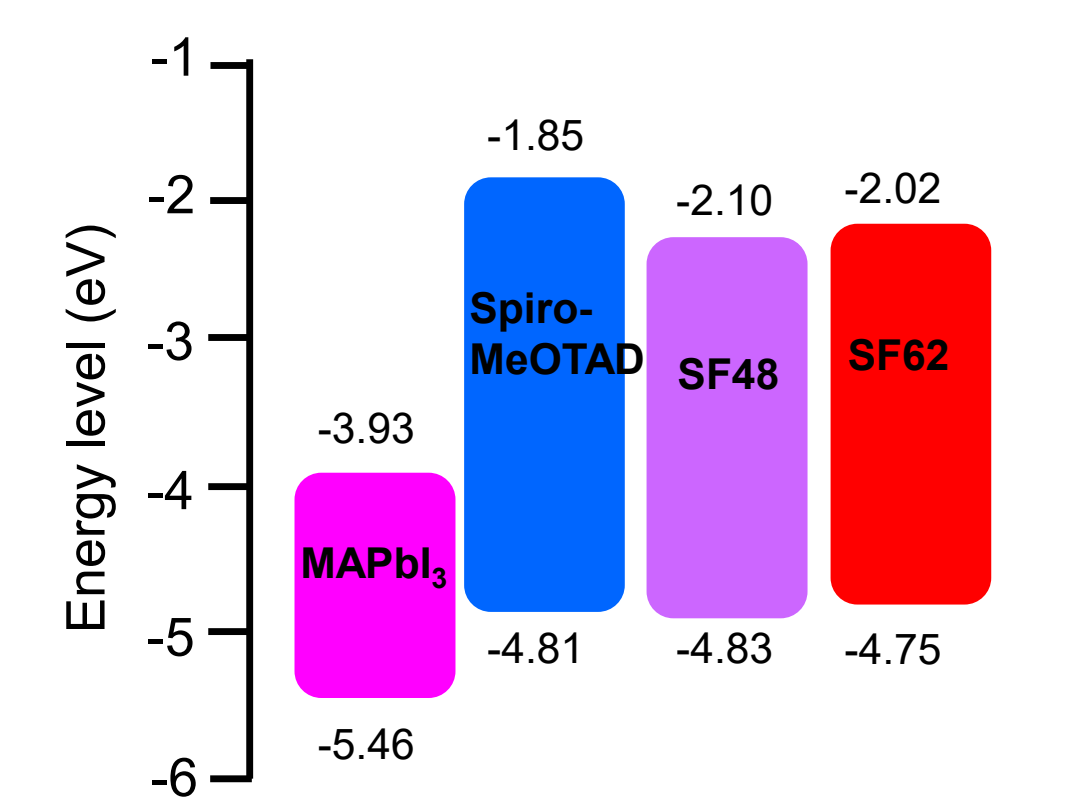


Figure 2. UV-vis spectra of the HTMs in solution (1×10^{-5} M in CB).

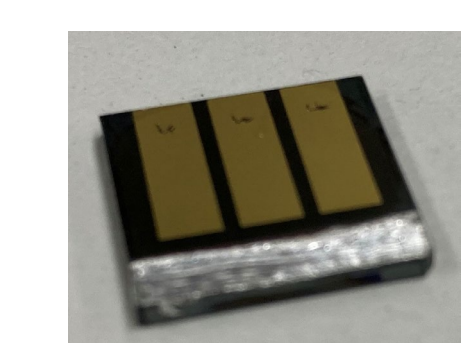


SF48 and SF62 have a suitable HOMO energy levels for hole extraction from perovskite.

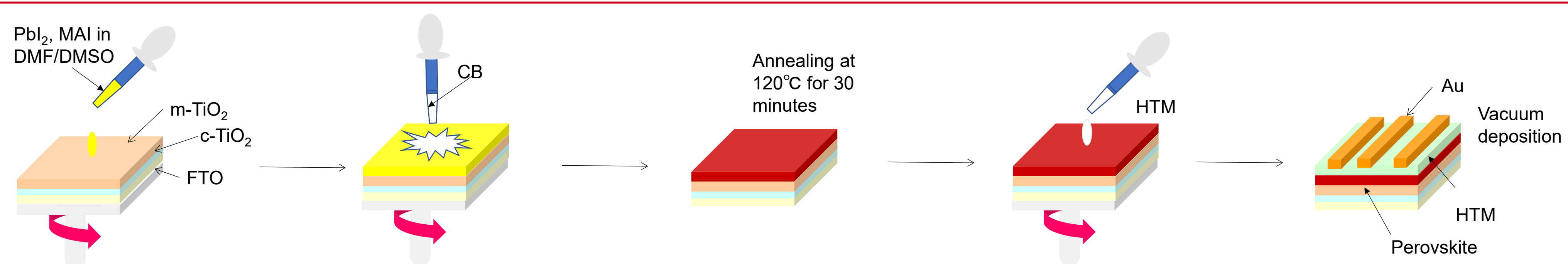
Figure 3. Energy diagram of the HTMs.

^a Nobuko Onozawa-Komatsuzaki et al, *ACS Appl. Energy Mater.* 2022, 5, 6633

Device Fabrication



1.5 cm x 1.5 cm
Active area 0.119 cm²



Results and Discussion

1. The photovoltaic data of the PSCs based on non-doped HTMs

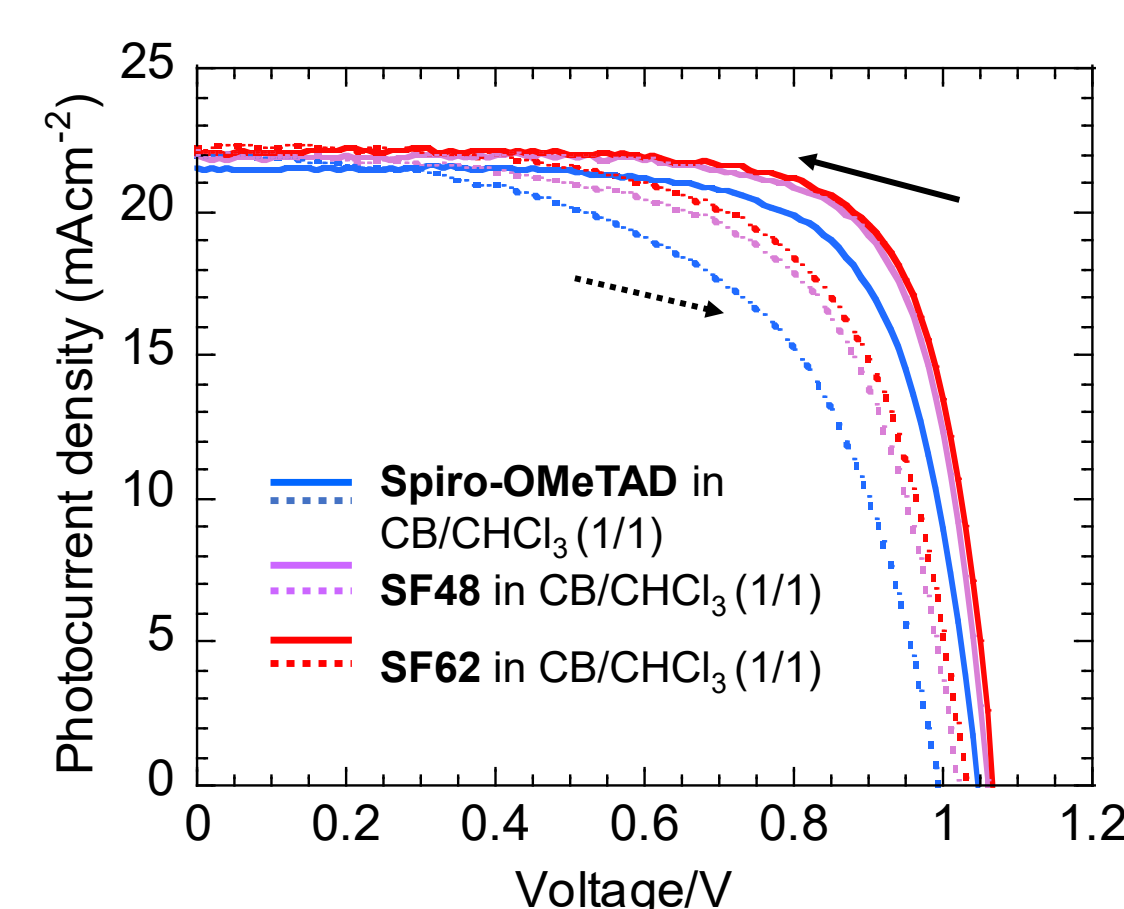


Figure 4. J-V curves for the PSCs with non-doped Spiro-OMeTAD, SF48, and SF62 using CB/CHCl₃ (1/1) as the solvent.

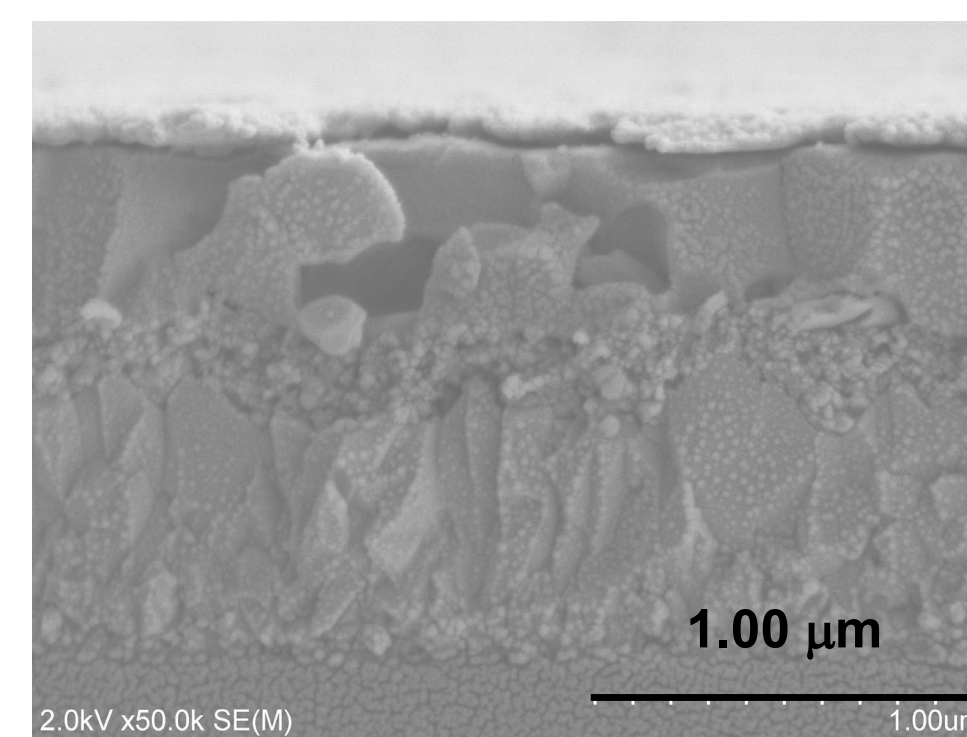
Table 1. Photovoltaic parameters of the PSCs for HTMs without dopants. (Thickness of HTMs; 20 nm)

	J_{sc} / mA cm ⁻²	V_{oc} / V	FF	PCE / %
Spiro-OMeTAD	21.9	1.01	0.67	12.5
SF48	22.4	1.01	0.67	15.2
SF62	21.8	1.03	0.67	15.1

The PSC based on non-doped SF48, 62 exhibited the higher PCE than that of Spiro-OMeTAD.

SF48, SF62 > Spiro-OMeTAD

2. SEM image



The optimal thickness of SF62 was only around 10%. SF62 is cost effective HTM.

Figure 5. Cross-sectional SEM image of SF62-based device.

3. Hole extraction ability

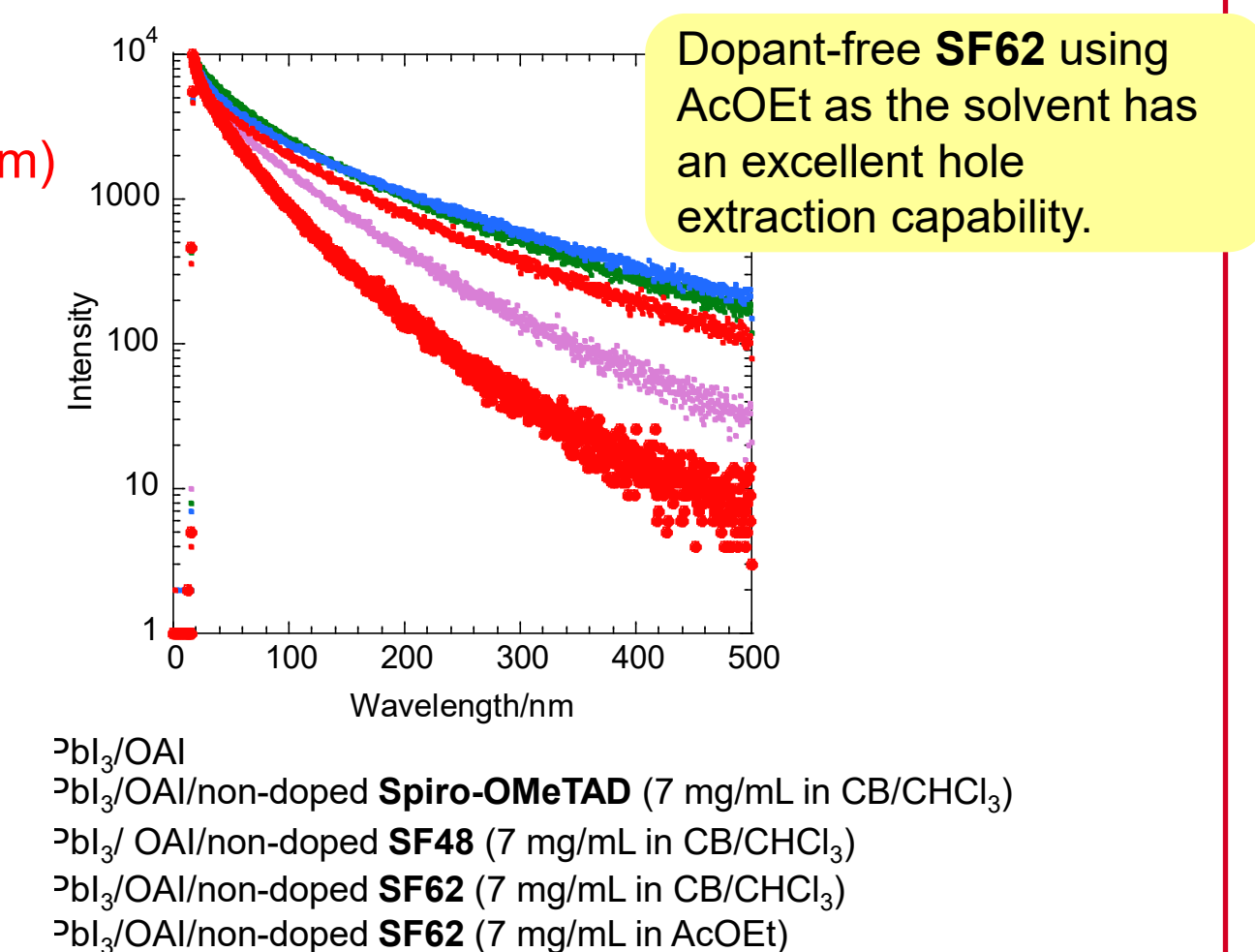


Figure 6. TRPL decay curves of the pristine perovskite and perovskite covered with non-doped HTM films excited at 532 nm.

4. The cell performance of the best PSC

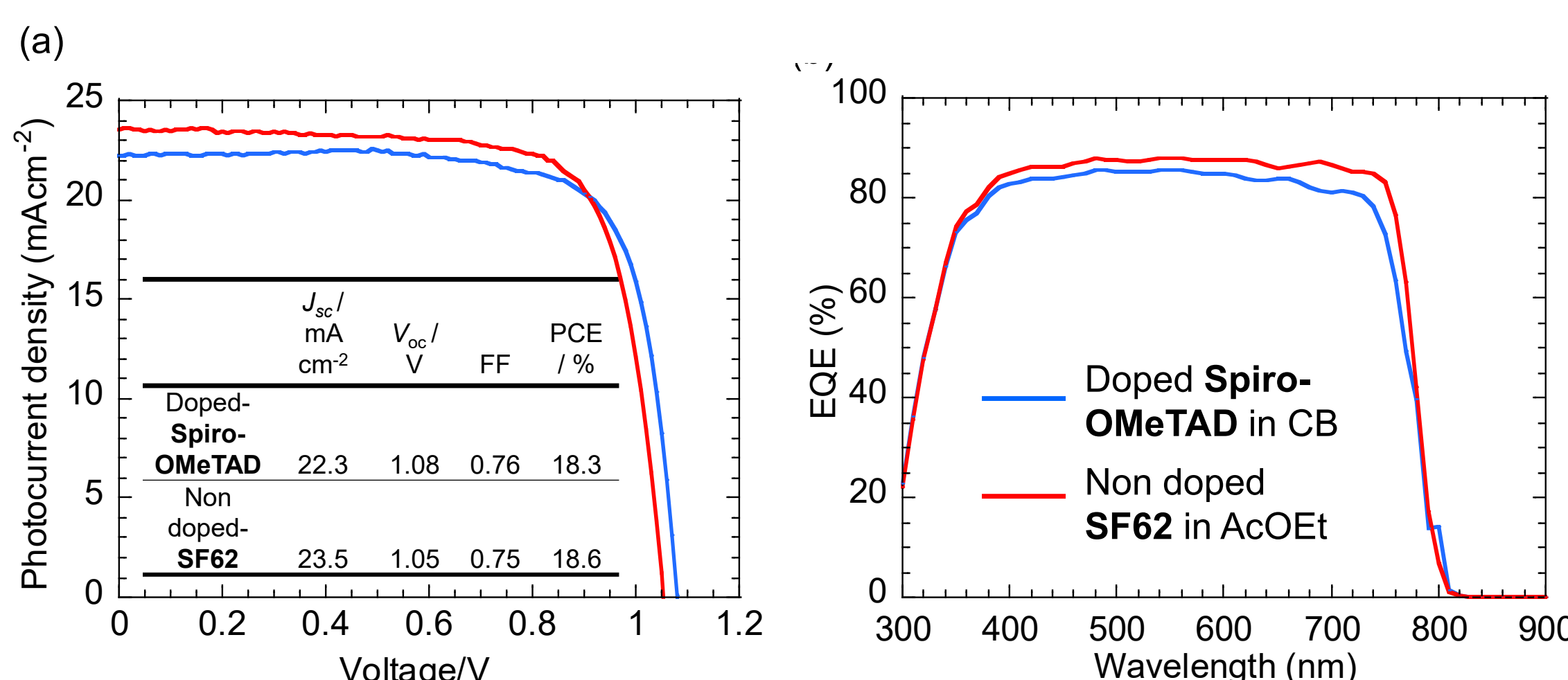


Figure 7. (a) J-V curves for the best-performing PSCs with non-doped SF62 using AcOEt as the solvent, along with doped Spiro-OMeTAD using CB as a reference and (b) EQE spectra of the same PSCs.

Table 2. Photovoltaic parameters of the PSCs with MAPbI₃ as the perovskite layer^a.

	J_{sc} / mA cm ⁻²	V_{oc} / V	FF	PCE / %
Spiro-OMeTAD with dopant (TBP, LiTFSI)				
FW	22.5 ± 0.5	1.02 ± 0.02	0.61 ± 0.02	14.0 ± 0.6
BW	22.0 ± 0.6	1.07 ± 0.02	0.73 ± 0.03	17.2 ± 0.9
SF62 without dopant				
FW	23.0 ± 0.3	0.99 ± 0.02	0.63 ± 0.04	14.2 ± 1.1
BW	22.9 ± 0.3	1.04 ± 0.01	0.74 ± 0.02	17.7 ± 0.6

^a Passivated with octylammonium iodide between the perovskite and HTL.

The PCE is higher than that for the doped Spiro-OMeTAD-based PSCs.

5. Thermal stability test

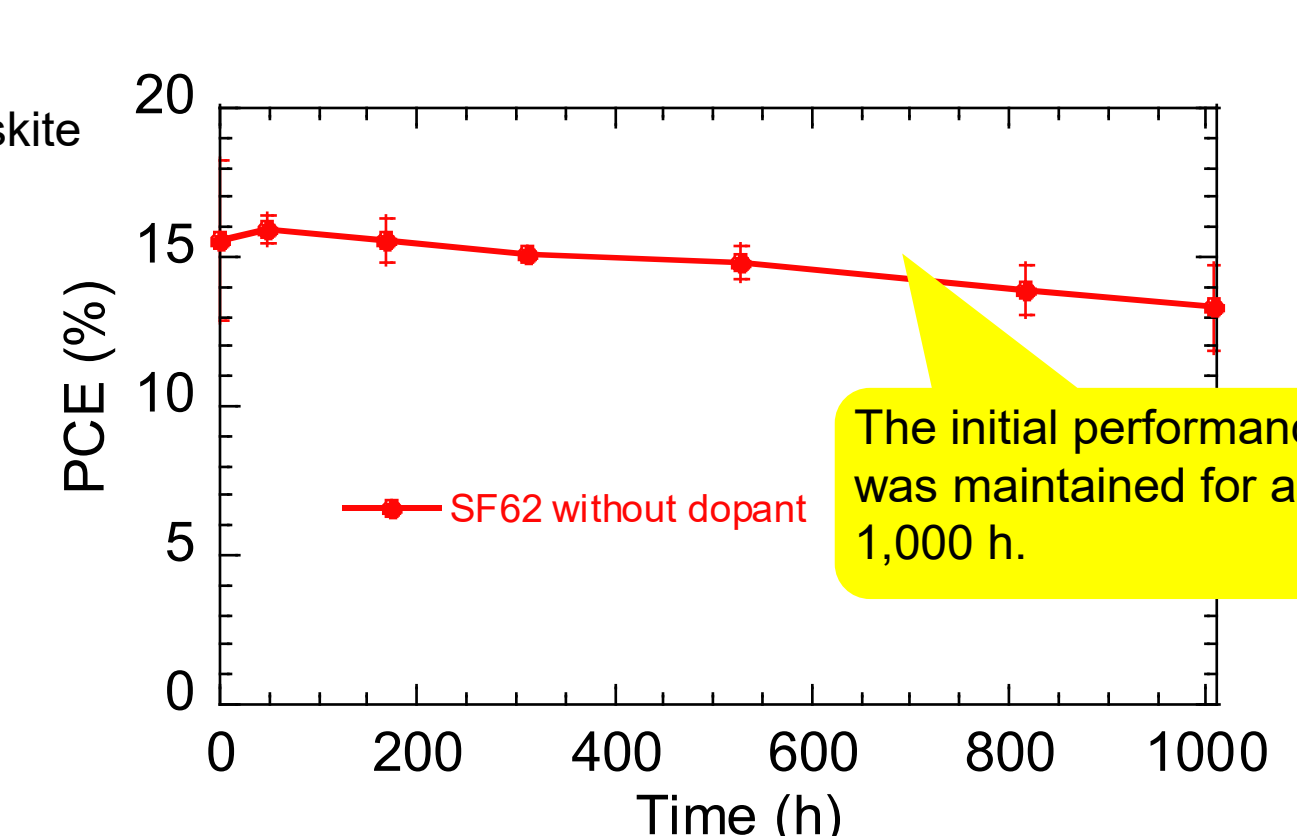


Figure 8. Change in the efficiencies of the solar cells based on non-doped SF62 at 85 °C in ambient air.

Summary

We developed a new compound SF62 and successfully applied it as a dopant-free HTM in PSCs. In particular, the HTL layer of SF62 was prepared using the nonhalogenated green solvent AcOEt. Consequently, the PCE of the device based on SF62 was 18.6%, comparable to that of the reference PSC with doped Spiro-OMeTAD (18.3%). Furthermore, the thermal stability of the PSC based on non-doped SF62 at 85 °C in ambient air was found to be superior to that of doped or non-doped Spiro-OMeTAD. [1]

[1] N. Onozawa-Komatsuzaki, D. Tsuchiya, S. Inoue, A. Kogo, T. Ueno and T. N. Murakami, *Appl. Phys. Express*, 2023, 16, 016502.

小野澤伸子¹、土屋大輔²、井上真一²、古郷敦史¹、村上拓郎¹

1. 産業技術総合研究所 ゼロエミッション国際共同研究センター, 2. 日本精化株式会社

